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(Not for submission under 37 CFR 1.99)

Application Number	09836449
Filing Date	2001-04-17
First Named Inventor	Stephen J. Fonash
Art Unit	2812
Examiner Name	Richard A. Booth
Attorney Docket Number	201009-007000

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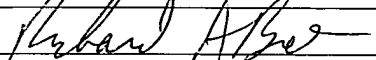
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RB	1	BAE ET AL., "Characteristics of amorphous and polycrystalline silicon films deposited at 120 C by electron cyclotron resonance-enhanced chemical vapor deposition," J. Vac. Sci. & Technol. A16(3), May/June 1998, pp. 1912-1916.	<input type="checkbox"/>
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